



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts,Customers Priority,Honest Operation,and Considerate Service",our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

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Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



P-Channel Power MOSFET

-20V, -2.8A, 100mΩ

Features

- Advance Trench Process Technology
- High Density Cell Design for Ultra Low On-resistance

KEY PERFORMANCE PARAMETERS

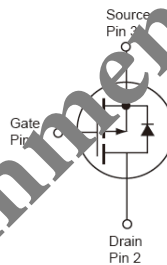
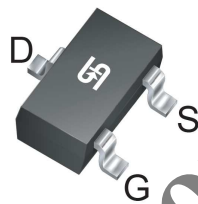
PARAMETER		VALUE	UNIT
V_{DS}		-20	V
$R_{DS(on)}$ (max)	$V_{GS} = -4.5V$	100	mΩ
	$V_{GS} = -2.5V$	150	
	$V_{GS} = -1.8V$	190	
Q_g		5.8	nC

Application

- Load Switch
- PA Switch



SOT-23



Notes: Moisture sensitivity level: level 3. Per J-STD-020

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V_{DS}	-20	V
Gate-Source Voltage		V_{GS}	± 8	V
Continuous Drain Current (Note 1)	$V_{GS} = 4.5V$	I_D	-2.8	A
Pulsed Drain Current (Note 2)	$V_{GS} = 4.5V$	I_{DM}	-8	A
Continuous Source Current (Diode Conduction)		I_S	-0.72	A
Total Power Dissipation	$T_A = 25^\circ\text{C}$	P_{DTOT}	0.9	W
	$T_A = 75^\circ\text{C}$		0.57	
Operating Junction and Storage Temperature Range		T_J, T_{STG}	- 55 to +150	$^\circ\text{C}$

THERMAL PERFORMANCE

PARAMETER	SYMBOL	LIMIT	UNIT
Junction to Ambient Thermal Resistance(PCB mounted)	$R_{\theta JA}$	120	$^\circ\text{C/W}$
Lead Temperature (1/8" from case)	T_L	5	S

Notes: $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. The case thermal reference is defined at the solder mounting surface of the drain pins. $R_{\theta JA}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design. $R_{\theta JA}$ shown below for single device operation on FR-4 PCB in still air.

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static (Note 3)						
Drain-Source Breakdown Voltage	V _{GS} = 0V, I _D = -250uA	BV _{DSS}	-20	--	--	V
Gate Threshold Voltage	V _{DS} = V _{GS} , I _D = -250μA	V _{GS(TH)}	-0.45	--	-0.95	V
Gate Body Leakage	V _{GS} = ±8V, V _{DS} = 0V	I _{GSS}	--	--	±100	nA
Zero Gate Voltage Drain Current	V _{DS} = -9.6V, V _{GS} = 0V	I _{DSS}	--	--	-1.0	μA
On-State Drain Current	V _{DS} ≥ -10V, V _{GS} = -5V	I _{D(ON)}	-6	--	--	A
Drain-Source On-State Resistance	V _{GS} = -4.5V, I _D = -2.8A	R _{DS(ON)}	--	80	100	mΩ
	V _{GS} = -2.5V, I _D = -2.0A		--	110	150	
	V _{GS} = -1.8V, I _D = -2.0A		--	150	190	
Forward Transconductance	V _{DS} = -5V, I _D = -4A	g _{fs}	--	6.5	--	S
Dynamic (Note 4)						
Total Gate Charge	V _{DS} = -6V, I _D = -2.8A, V _{GS} = -4.5V	Q _g	--	5.8	--	nC
Gate-Source Charge		Q _{gs}	--	0.85	--	
Gate-Drain Charge		Q _{gd}	--	1.7	--	
Input Capacitance	V _{DS} = -6V, V _{GS} = 0V, f = 1.0MHz	C _{iss}	--	415	--	pF
Output Capacitance		C _{oss}	--	223	--	
Reverse Transfer Capacitance		C _{rss}	--	87	--	
Switching (Note 5)						
Turn-On Delay Time	V _{DS} = -6V, R _L = 6Ω, I _D = -1A, V _{GEN} = -4.5V, R _G = 6Ω	t _{d(on)}	--	13	--	ns
Turn-On Rise Time		t _r	--	36	--	
Turn-Off Delay Time		t _{d(off)}	--	42	--	
Turn-Off Fall Time		t _f	--	34	--	
Source-Drain Diode (Note 3)						
Forward On Voltage	I _S = -0.75A, V _{GS} = 0V	V _{SD}	--	- 0.8	-1.2	V

Notes:

1. Pulse width limited by the maximum junction temperature.
2. Surface Mounted on FR4 Board, $t \leq 5$ sec.
3. Pulse test: $PW \leq 300\mu s$, duty cycle $\leq 2\%$.
4. For DESIGN AID ONLY, not subject to production testing.
5. Switching time is essentially independent of operating temperature.

ORDERING INFORMATION

PART NO.	PACKAGE	PACKING
TSM2301BCX RFG	SOT-23	3,000pcs / 7"Reel

Note:

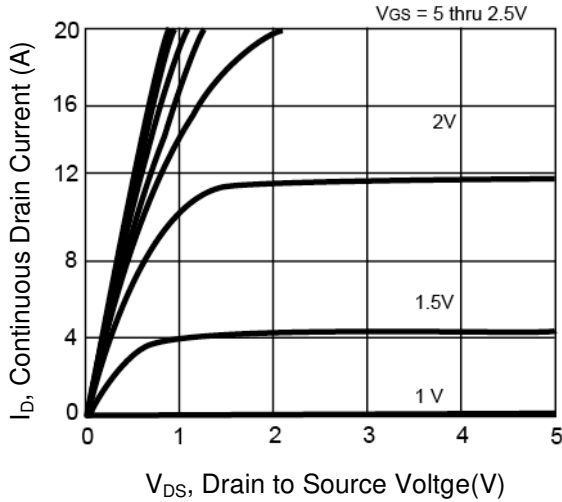
1. Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
2. Halogen-free according to IEC 61249-2-21 definition

Not Recommended

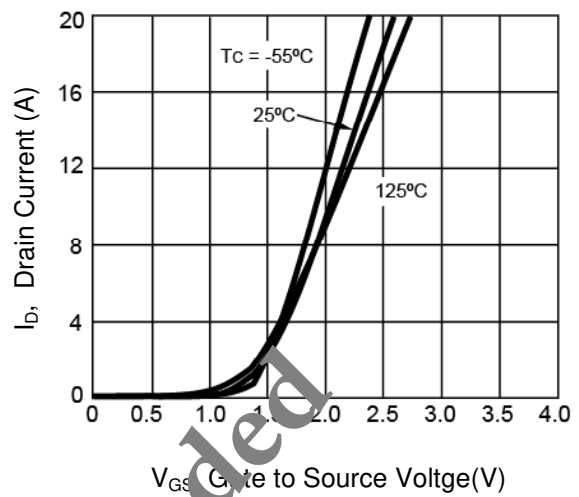
CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

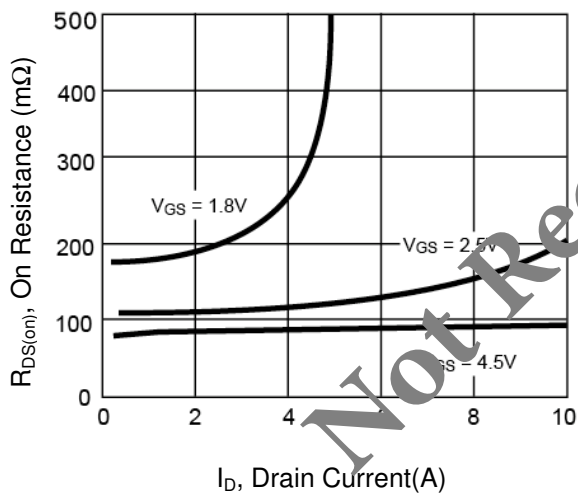
Output Characteristics



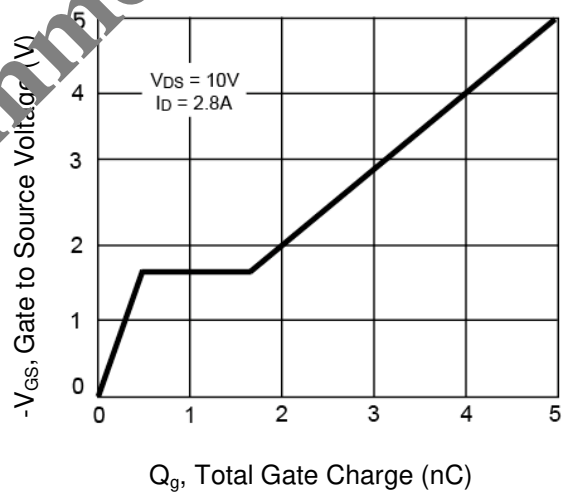
Transfer Characteristics



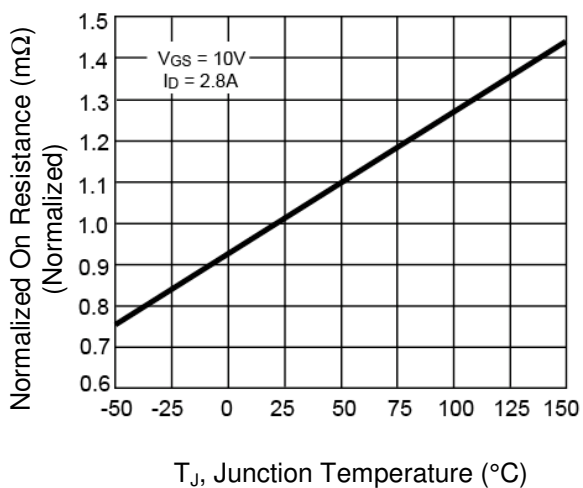
On-Resistance vs. Drain Current



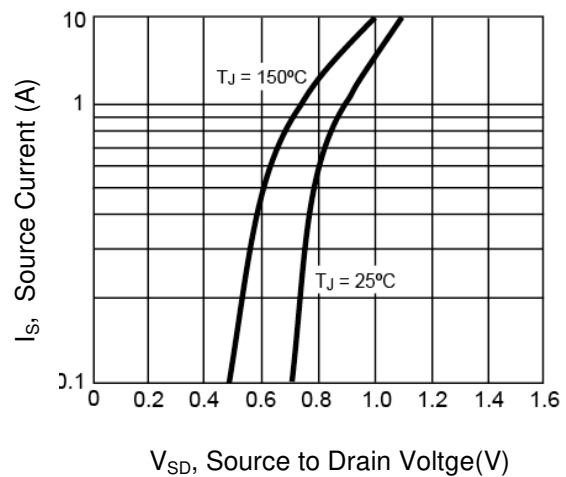
Gate Charge



On-Resistance vs. Junction Temperature



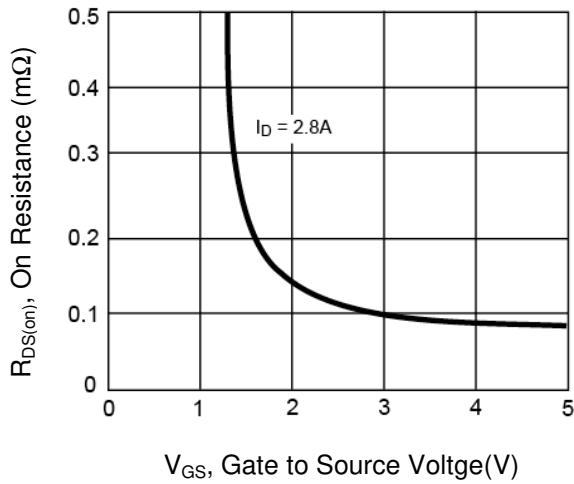
Source-Drain Diode Forward Voltage



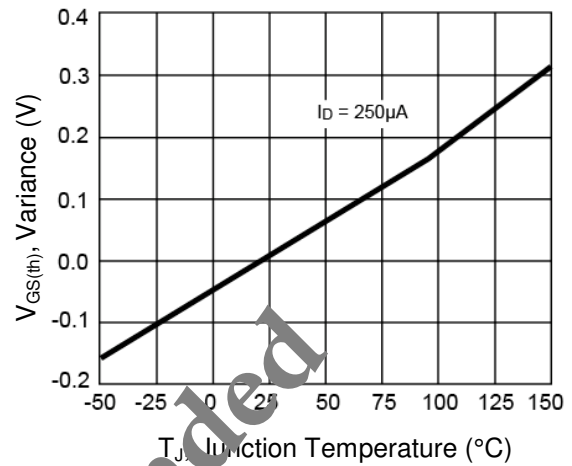
CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

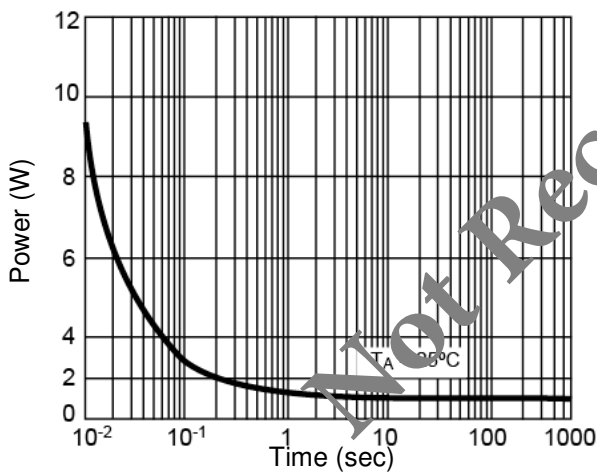
On-Resistance vs. Gate-Source Voltage



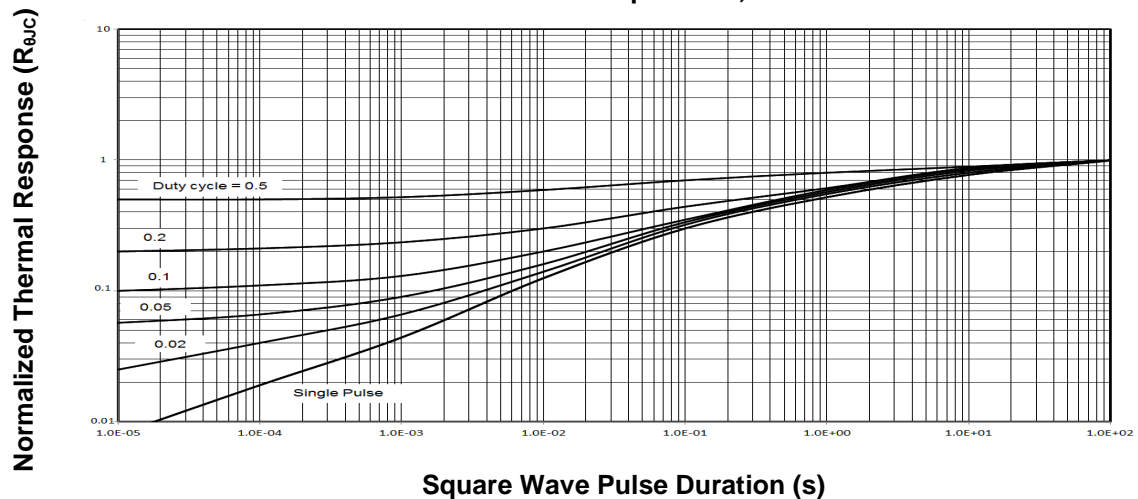
Threshold Voltage



Single Pulse Power

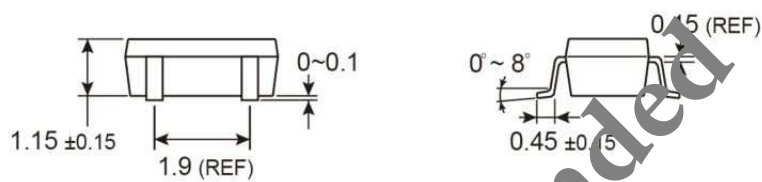
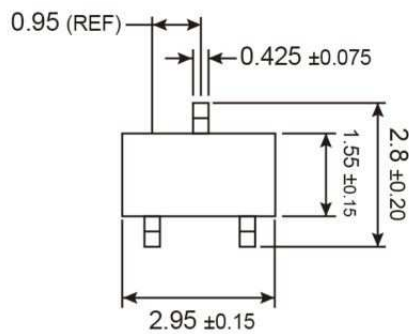


Normalized Thermal Transient Impedance, Junction-to-Ambient

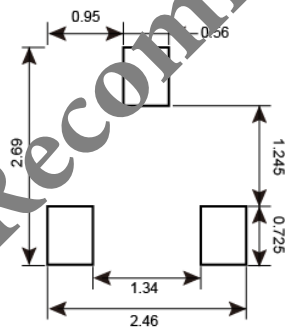


PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

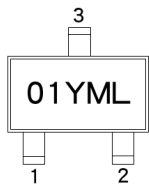
SOT-23



SUGGESTED PAD LAYOUT (Unit: Millimeters)



MARKING DIAGRAM



- 01** = Device Code
Y = Year Code
M = Month Code for Halogen Free Product
O =Jan **P** =Feb **Q** =Mar **R** =Apr
S =May **T** =Jun **U** =Jul **V** =Aug
W =Sep **X** =Oct **Y** =Nov **Z** =Dec
L = Lot Code

Not Recommended

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